Comparators

Input Full Swing, Open Drain Output Low Supply Current CMOS Comparators

BU7230G BU7230SG BU7233F BU7233SF

General Description

BU7230G/BU7233F are input full swing and open drain comparators. BU7230SG/BU7233SF have an expanded operating temperature range. These features low operating supply voltage of +1.8V to +5.5V, low supply current and extremely low input bias current.

Features

- Low Operating Supply Voltage
- Low Supply Current
- Input Full Swing
- Open Drain Output Type
- Wide Operating Temperature Range
- Low Input Bias Current

Applications

- Battery Monitor
- Mobile Equipments
- Limit Comparator
- Consumer Electronics

Key Specifications

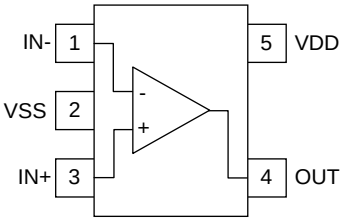
- Operating Supply Voltage:
  - Single Supply: +1.8V to +5.5V
  - Split Supply: ±0.9V to ±2.75V
- Supply Current:
  - BU7230G/BU7230SG: 5µA
  - BU7233F/BU7233SF: 10µA
- Temperature Range:
  - BU7230G/BU7233F: -40°C to +85°C
  - BU7230SG/BU7233SF: -40°C to +105°C
- Input Offset Current: 1pA (Typ)
- Input Bias Current: 1pA (Typ)

Packages

	W(Typ) x D(Typ) x H(Max)
SSOP5	2.90mm x 2.80mm x 1.25mm
SOP8	5.00mm x 6.20mm x 1.71mm

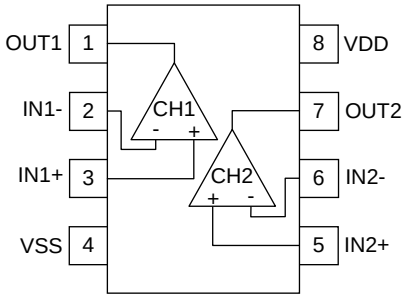
Pin Configuration

BU7230G, BU7230SG: SSOP5



Pin No.	Pin Name
1	IN-
2	VSS
3	IN+
4	OUT
5	VDD

BU7233F, BU7233SF: SOP8



Pin No.	Pin Name
1	OUT1
2	IN1-
3	IN1+
4	VSS
5	IN2+
6	IN2-
7	OUT2
8	VDD

○Product structure：Silicon monolithic integrated circuit ○This product has no designed protection against radioactive rays.

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Package	
SSOP5	SOP8
BU7230G BU7230SG	BU7233F BU7233SF

Ordering Information

B U 7 2 3 x x x - x x

Part Number
BU7230G
BU7230SG
BU7233F
BU7233SF

Package
G : SSOP5
F : SOP8

Packaging and Forming Specification
TR: Embossed Tape and Reel (SSOP5)
E2: Embossed Tape and Reel (SOP8)

Line-up

T_{opr}	Channels	Package		Orderable Part Number
-40°C to +85°C	1ch	SSOP5	Reel of 3000	BU7230G-TR
	2ch	SOP8	Reel of 2500	BU7233F-E2
-40°C to +105°C	1ch	SSOP5	Reel of 3000	BU7230SG-TR
	2ch	SOP8	Reel of 2500	BU7233SF-E2

Absolute Maximum Ratings (T_A=25°C)

Parameter	Symbol		Rating				Unit
			BU7230G	BU7233F	BU7230SG	BU7233SF	
Supply Voltage	VDD-VSS		+7				V
Power Dissipation	P_D	SSOP5	0.54 (Note 1,3)	-	0.54 (Note 1,3)	-	W
		SOP8	-	0.55 (Note 2,3)	-	0.55 (Note 2,3)	
Differential Input Voltage (Note 4)	V_{ID}		VDD - VSS				V
Input Common-mode Voltage Range	V_{ICM}		(VSS-0.3) to (VDD+0.3)				V
Input Current (Note 5)	I_I		±10				mA
Operating Supply Voltage	V_{opr}		+1.8 to +5.5 ±0.9 to ±2.75				V
Operating Temperature	T_{opr}		-40 to +85		-40 to +105		°C
Storage Temperature	T_{stg}		-55 to +125				°C
Maximum Junction Temperature	T_{Jmax}		+125				°C

(Note 1) To use at temperature above T_A=25°C reduce 5.4mW/°C.
(Note 2) To use at temperature above T_A=25°C reduce 5.5mW/°C.
(Note 3) Mounted on a FR4 glass epoxy PCB 70mm×70mm×1.6mm (Copper foil area less than 3%).
(Note 4) The voltage difference between inverting input and non-inverting input is the differential input voltage. Then input pin voltage is set to more than VSS.
(Note 5) An excessive input current will flow when input voltages of more than VDD+0.6V or less than VSS-0.6V are applied. The input current can be set to less than the rated current by adding a limiting resistor.
Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

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Electrical Characteristics

○BU7230G, BU7230SG（Unless otherwise specified VDD=+3V, VSS=0V, T_A=25°C）

Parameter	Symbol	Temperature Range	Limit			Unit	Conditions
			Min	Typ	Max		
Input Offset Voltage (Note 6)	V_{IO}	25°C	-	1	11	mV	-
Input Offset Current (Note 6)	I_{IO}	25°C	-	1	-	pA	-
Input Bias Current (Note 6)	I_B	25°C	-	1	-	pA	-
Supply Current (Note 7)	I_{DD}	25°C	-	5	15	μA	R_L=∞
		Full Range	-	-	30		
Maximum Output Voltage(High)	V_{OH}	25°C	VDD-0.1	-	-	V	R_L=10kΩ, V_{RL}=3V
Maximum Output Voltage(Low)	V_{OL}	25°C	-	-	VSS+0.1	V	R_L=10kΩ
Large Signal Voltage Gain	A_V	25°C	-	90	-	dB	R_L=10kΩ
Input Common-mode Voltage Range	V_{ICM}	25°C	0	-	3	V	VSS to VDD
Common-mode Rejection Ratio	CMRR	25°C	-	80	-	dB	-
Power Supply Rejection Ratio	PSRR	25°C	-	80	-	dB	-
Output Sink Current (Note 8)	I_{SINK}	25°C	3	6	-	mA	OUT=VSS+0.4V
Output Fall Time	t_F	25°C	-	20	-	ns	R_L=10kΩ V_{RL}=3V C_L=15pF IN-=1.5V 100mV Overdrive
Propagation Delay Time L to H	t_{PLH}	25°C	-	1.8	-	μs	
Propagation Delay Time H to L	t_{PHL}	25°C	-	0.6	-	μs	

(Note 6) Absolute value
(Note 7) Full range: BU7230G: T_A=-40°C to +85°C BU7230SG: T_A=-40°C to +105°C
(Note 8) Under the high temperature environment, consider the power dissipation of IC when selecting the output current.
When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

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Electrical Characteristics - continued

○BU7233F, BU7233SF（Unless otherwise specified VDD=+3V, VSS=0V, T_A=25°C）

Parameter	Symbol	Temperature Range	Limit			Unit	Conditions
			Min	Typ	Max		
Input Offset Voltage (Note 9)	V_{IO}	25°C	-	1	11	mV	-
Input Offset Current (Note 9)	I_{IO}	25°C	-	1	-	pA	-
Input Bias Current (Note 9)	I_B	25°C	-	1	-	pA	-
Supply Current (Note 10)	I_{DD}	25°C	-	10	25	μA	R_L=∞ All Comparators
		Full Range	-	-	50		
Maximum Output Voltage(High)	V_{OH}	25°C	VDD-0.1	-	-	V	R_L=10kΩ, V_{RL}=3V
Maximum Output Voltage(Low)	V_{OL}	25°C	-	-	VSS+0.1	V	R_L=10kΩ
Large Signal Voltage Gain	A_V	25°C	-	90	-	dB	R_L=10kΩ
Input Common-mode Voltage Range	V_{ICM}	25°C	0	-	3	V	VSS to VDD
Common-mode Rejection Ratio	CMRR	25°C	-	80	-	dB	-
Power Supply Rejection Ratio	PSRR	25°C	-	80	-	dB	-
Output Sink Current (Note 11)	I_{SINK}	25°C	3	6	-	mA	OUT=VSS+0.4V
Output Fall Time	t_F	25°C	-	20	-	ns	R_L=10kΩ V_{RL}=3V C_L=15pF IN-=1.5V 100mV Overdrive
Propagation Delay Time L to H	t_{PLH}	25°C	-	1.8	-	μs	
Propagation Delay Time H to L	t_{PHL}	25°C	-	0.6	-	μs	

(Note 9) Absolute value

(Note 10) Full range: BU7233F: T_A=-40°C to +85°C BU7233SF: T_A=-40°C to +105°C

(Note 11) Under the high temperature environment, consider the power dissipation of IC when selecting the output current.
When the terminal short circuits are continuously output, the output current is reduced to climb to the temperature inside IC.

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Description of Electrical Characteristics

Described below are descriptions of the relevant electrical terms used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacturer's document or general document.

1. Absolute Maximum Ratings

Absolute maximum rating items indicate the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

(1) Supply Voltage (VDD/VSS)
Indicates the maximum voltage that can be applied between the VDD terminal and VSS terminal without deterioration or destruction of characteristics of internal circuit.

(2) Differential Input Voltage (V_{ID})
Indicates the maximum voltage that can be applied between non-inverting and inverting terminals without damaging the IC.

(3) Input Common-mode Voltage Range (V_{ICM})
Indicates the maximum voltage that can be applied to the non-inverting and inverting terminals without deterioration or destruction of electrical characteristics. Input common-mode voltage range of the maximum ratings does not assure normal operation of IC. For normal operation, use the IC within the input common-mode voltage range characteristics.

(4) Power Dissipation (P_D)
Indicates the power that can be consumed by the IC when mounted on a specific board at the ambient temperature 25°C (normal temperature). As for package product, P_D is determined by the temperature that can be permitted by the IC in the package (maximum junction temperature) and the thermal resistance of the package.

2. Electrical Characteristics

(1) Input Offset Voltage (V_{IO})
Indicates the voltage difference between non-inverting terminal and inverting terminals. It can be translated into the input voltage difference required for setting the output voltage at 0 V.

(2) Input Offset Current (I_{IO})
Indicates the difference of input bias current between the non-inverting and inverting terminals.

(3) Input Bias Current (I_B)
Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias currents at the non-inverting and inverting terminals.

(4) Supply Current (I_{DD})
Indicates the current that flows within the IC under specified no-load conditions.

(5) Maximum Output Voltage(High) / Maximum Output Voltage(Low) (V_{OH}/V_{OL})
Indicates the voltage range of the output under specified load condition. It is typically divided into maximum output voltage High and low. Maximum output voltage high indicates the upper limit of output voltage. Maximum output voltage low indicates the lower limit.

(6) Large Signal Voltage Gain (A_V)
Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage.
Av = (Output voltage) / (Differential input voltage)

(7) Input Common-mode Voltage Range (V_{ICM})
Indicates the input voltage range where IC normally operates.

(8) Common-mode Rejection Ratio (CMRR)
Indicates the ratio of fluctuation of input offset voltage when the input common mode voltage is changed. It is normally the fluctuation of DC.
CMRR = (Change of input common-mode voltage)/(Input offset fluctuation)

(9) Power Supply Rejection Ratio (PSRR)
Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed.
It is normally the fluctuation of DC.
PSRR= (Change of power supply voltage)/(Input offset fluctuation)

(10) Output Sink Current (I_{SINK})
The maximum current that can be output from the IC under specific output conditions. The output sink current indicates the current flowing into the IC.

(11) Output Fall Time (t_F)
Indicates the time required for an output voltage step to change from 90% to 10% of its final value.

(12) Propagation Delay Time L to H /Propagation Delay Time H to L (t_{PLH} / t_{PHL})
Indicates the time to reach 50% of the output voltage after the step voltage is applied at the input pin.

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Typical Performance Curves

○BU7230G, BU7230SG

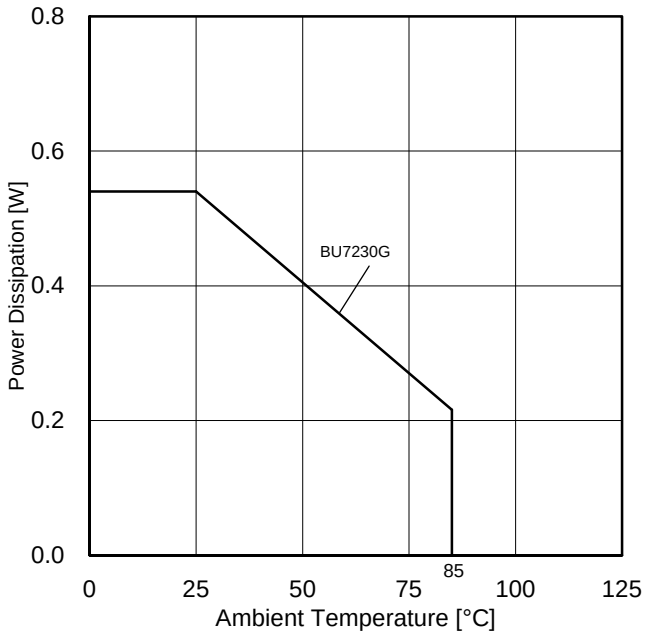


Figure 1.
Power Dissipation vs Ambient Temperature
(Derating Curve)

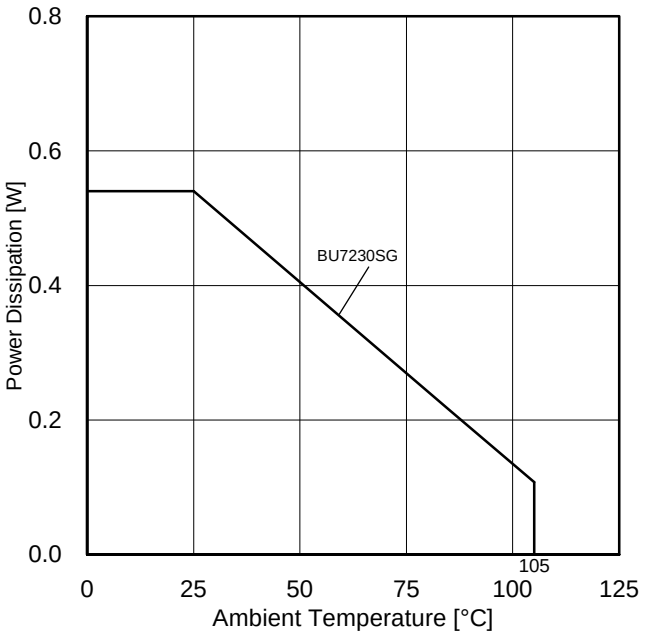


Figure 2.
Power Dissipation vs Ambient Temperature
(Derating Curve)

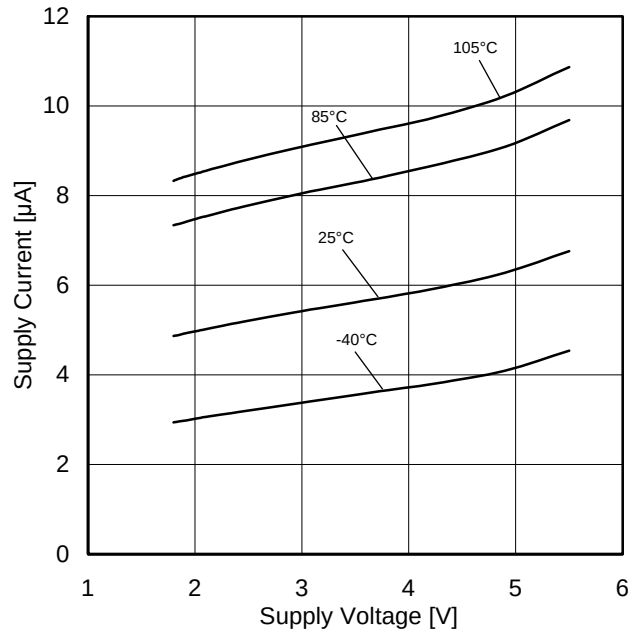


Figure 3.
Supply Current vs Supply Voltage

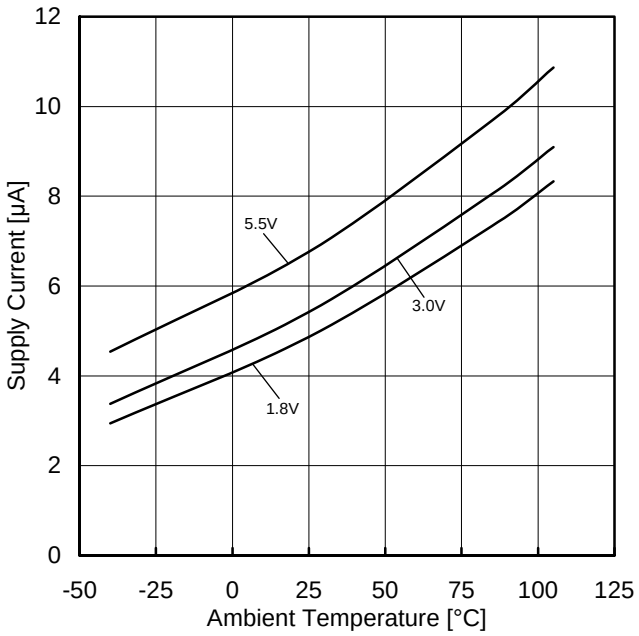


Figure 4.
Supply Current vs Ambient Temperature

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7230G: -40°C to +85°C BU7230SG: -40°C to +105°C

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Typical Performance Curves - continued

○BU7230G, BU7230SG

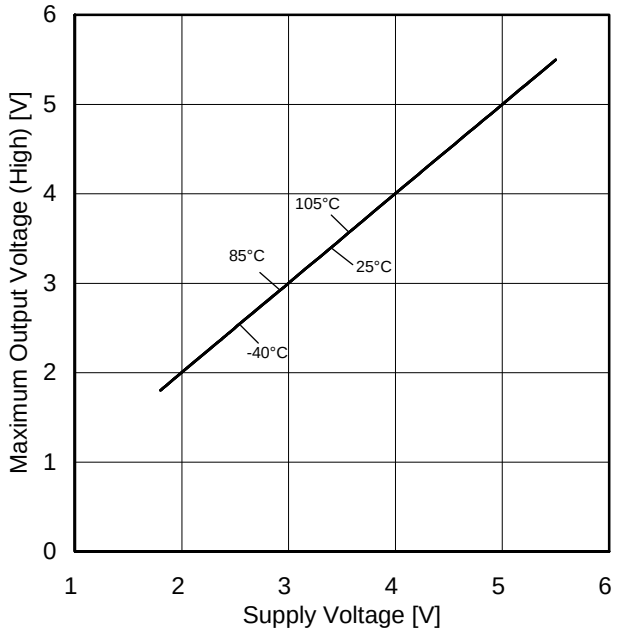


Figure 5.
Maximum Output Voltage (High) vs Supply Voltage
(R_L=10kΩ, V_{RL}=VDD)

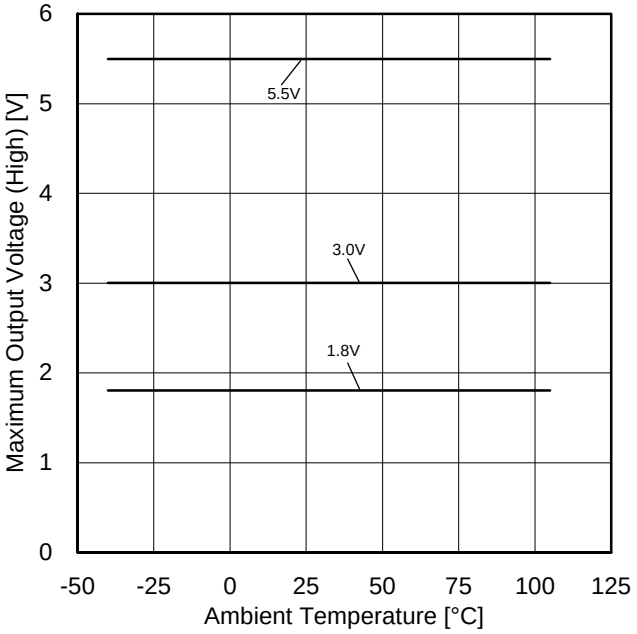


Figure 6.
Maximum Output Voltage (High) vs Ambient Temperature
(R_L=10kΩ, V_{RL}=VDD)

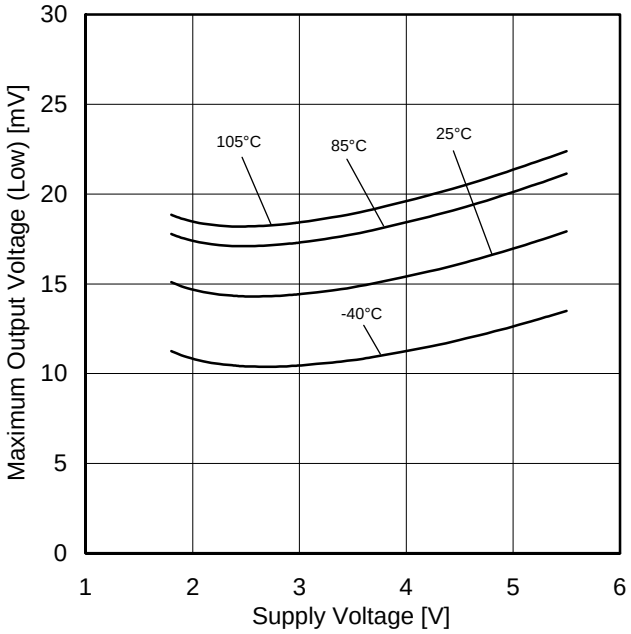


Figure 7.
Maximum Output Voltage (Low) vs Supply Voltage
(R_L=10kΩ)

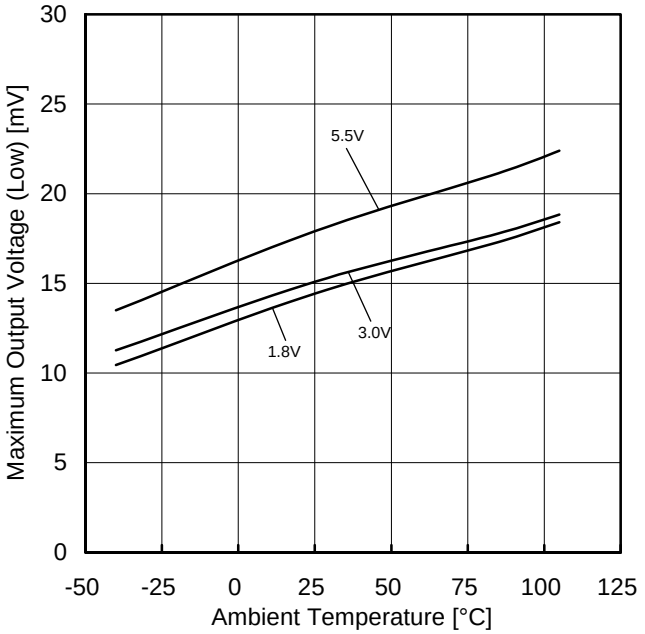


Figure 8.
Maximum Output Voltage (Low) vs Ambient Temperature
(R_L=10kΩ)

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7230G: -40°C to +85°C BU7230SG: -40°C to +105°C

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Typical Performance Curves - continued

○BU7230G, BU7230SG

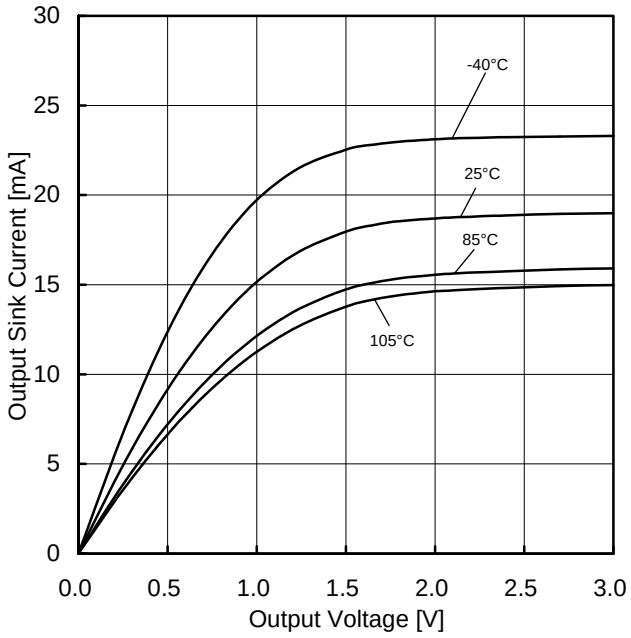


Figure 9.
Output Sink Current vs Output Voltage
(VDD=3V)

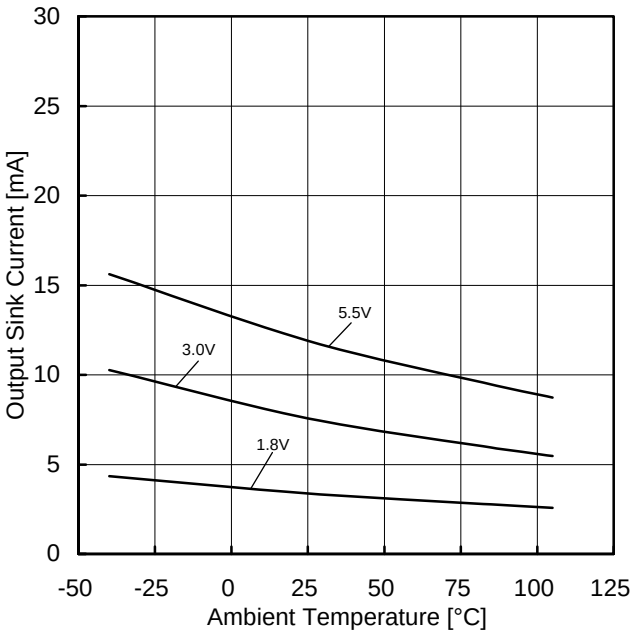


Figure 10.
Output Sink Current vs Ambient Temperature
(OUT=VSS+0.4V)

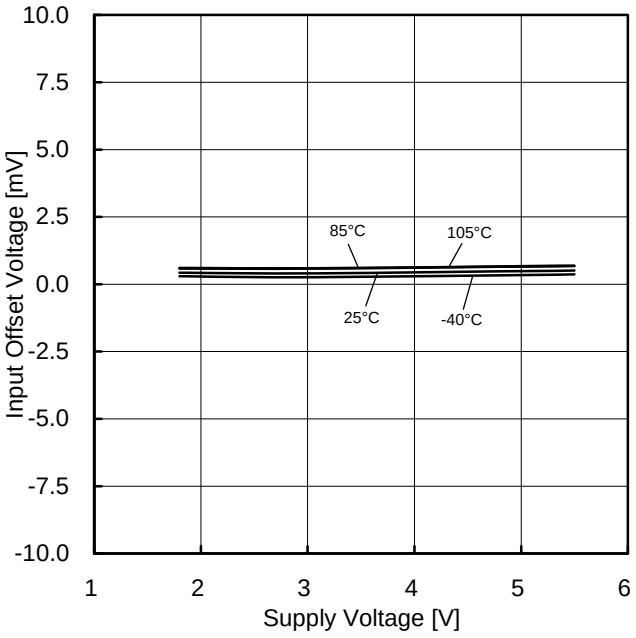


Figure 11.
Input Offset Voltage vs Supply Voltage
(V_{ICM}=VDD, E_K=-VDD/2)

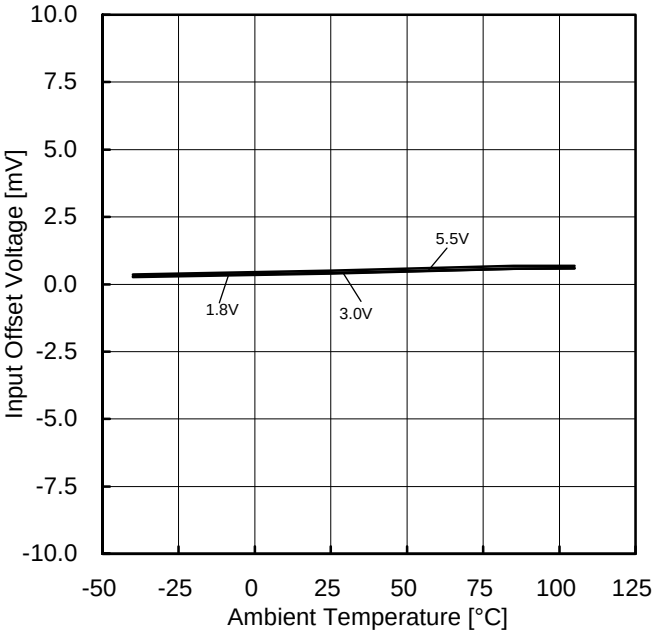


Figure 12.
Input Offset Voltage vs Ambient Temperature
(V_{ICM}=VDD, E_K=-VDD/2)

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7230G: -40°C to +85°C BU7230SG: -40°C to +105°C

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Typical Performance Curves - continued

○BU7230G, BU7230SG

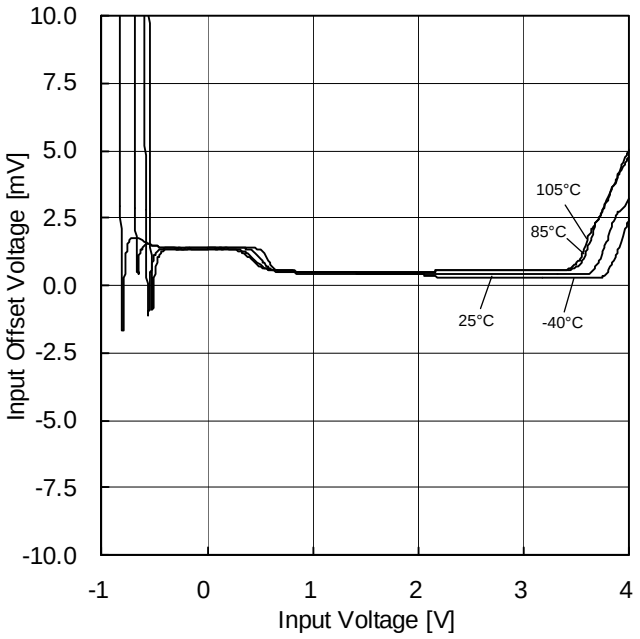


Figure 13.
Input Offset Voltage vs Input Voltage
(VDD=3V)

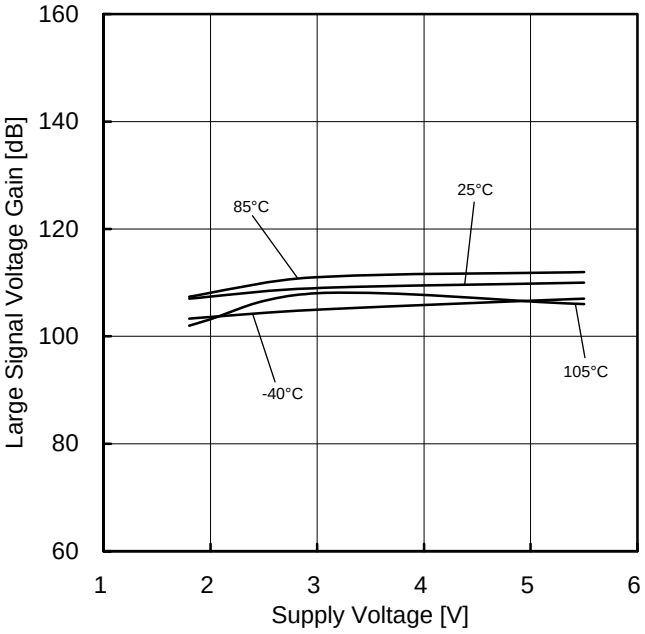


Figure 14.
Large Signal Voltage Gain vs Supply Voltage

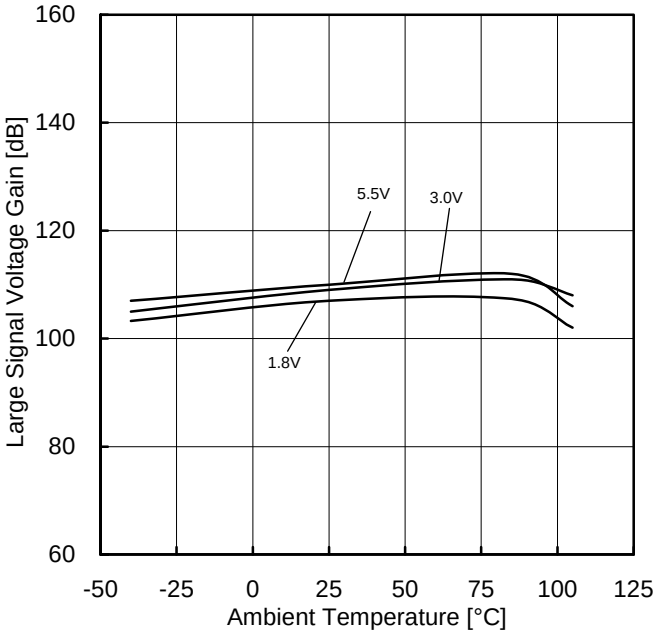


Figure 15.
Large Signal Voltage Gain vs Ambient Temperature

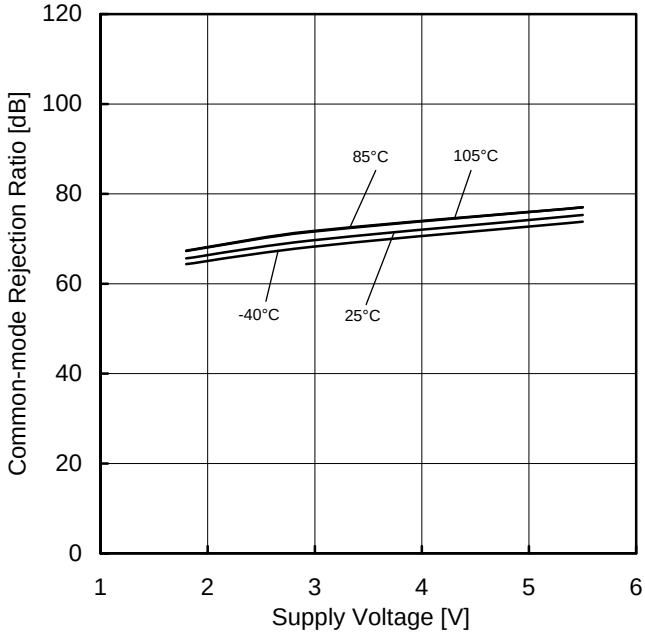


Figure 16.
Common-mode Rejection Ratio vs Supply Voltage

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7230G: -40°C to +85°C BU7230SG: -40°C to +105°C

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Typical Performance Curves - continued

○BU7230G, BU7230SG

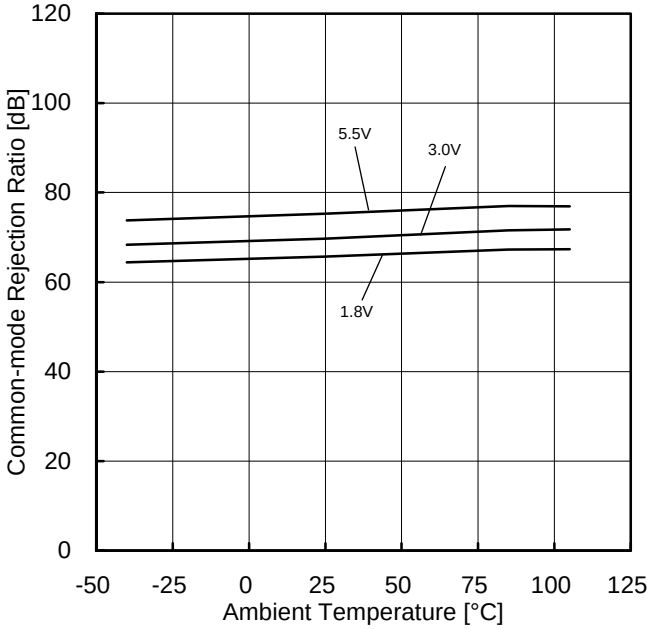


Figure 17.
Common-mode Rejection Ratio vs Ambient Temperature

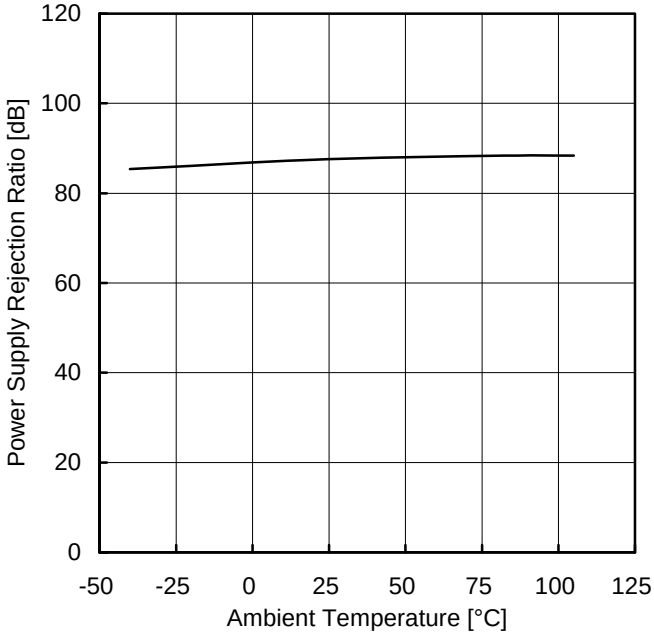


Figure 18.
Power Supply Rejection Ratio vs Ambient Temperature

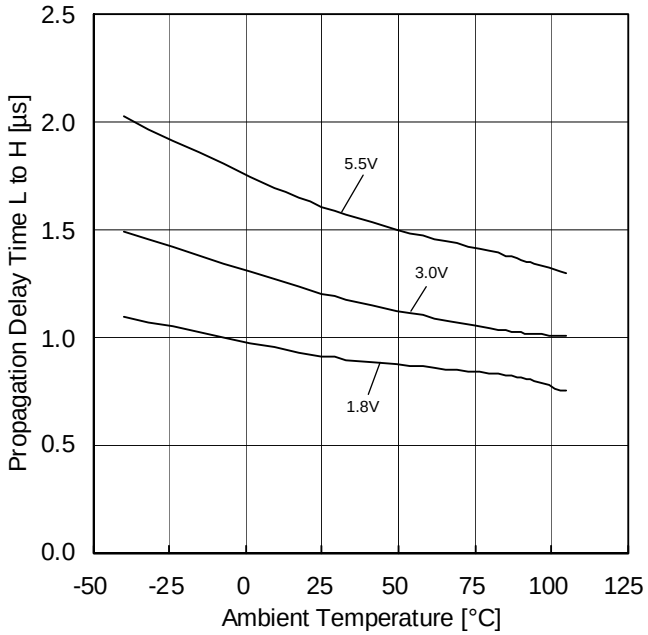


Figure 19.
Propagation Delay Time L to H vs Ambient Temperature
(R_L=10kΩ, V_{RL}=3V, C_L=15pF
IN-=1.5V, 100mV Overdrive)

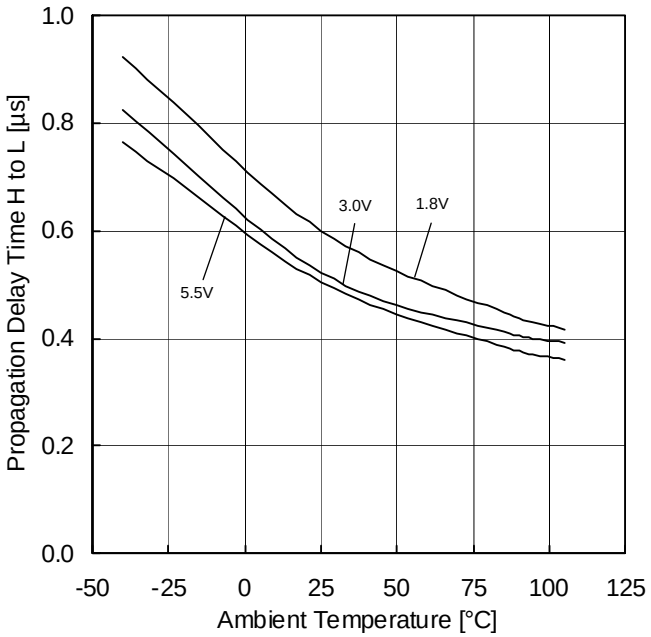


Figure 20.
Propagation Delay Time H to L vs Ambient Temperature
(R_L=10kΩ, V_{RL}=3V, C_L=15pF
IN-=1.5V, 100mV Overdrive)

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7230G: -40°C to +85°C BU7230SG: -40°C to +105°C

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Typical Performance Curves - continued

○BU7233F, BU7233SF

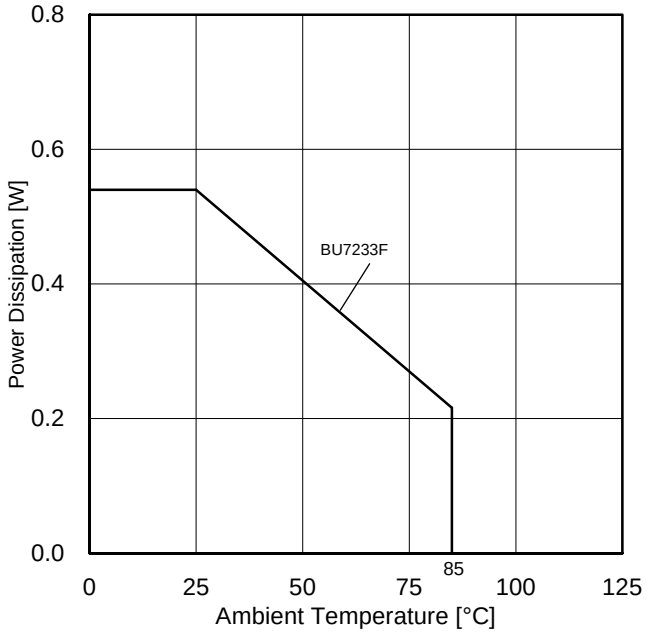


Figure 21.
Power Dissipation vs Ambient Temperature
(Derating Curve)

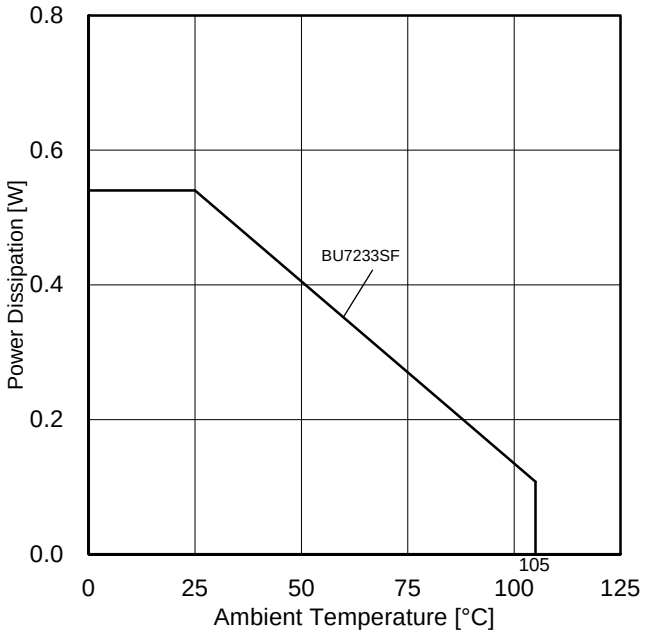


Figure 22.
Power Dissipation vs Ambient Temperature
(Derating Curve)

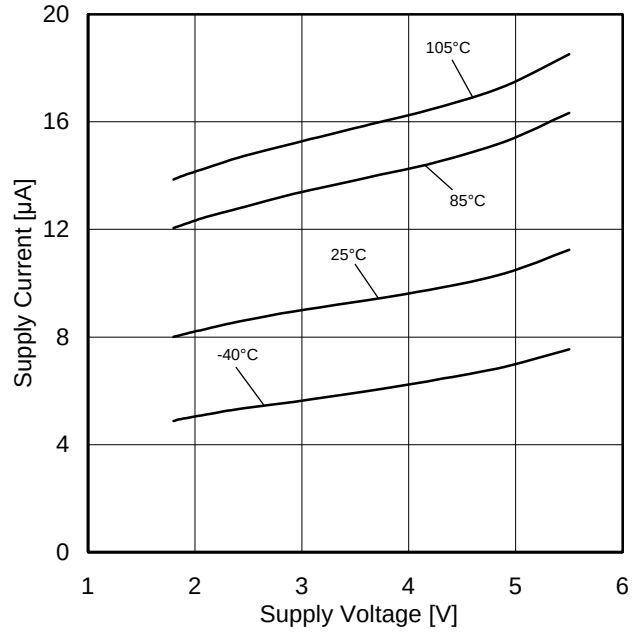


Figure 23.
Supply Current vs Supply Voltage

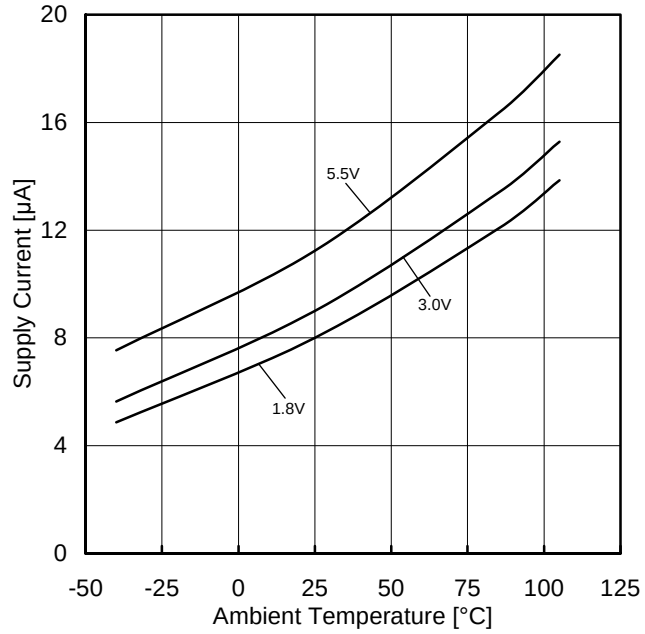


Figure 24.
Supply Current vs Ambient Temperature

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7233F: -40°C to +85°C BU7233SF: -40°C to +105°C

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Typical Performance Curves - continued

○BU7233F, BU7233SF

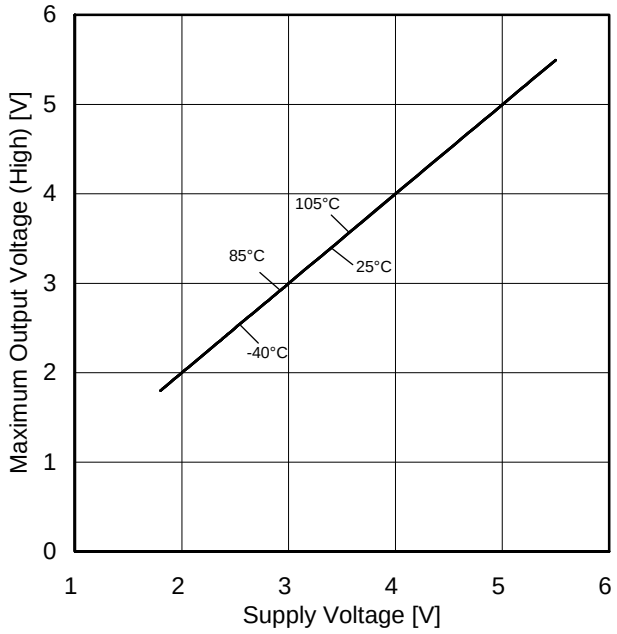


Figure 25.
Maximum Output Voltage (High) vs Supply Voltage
(R_L=10kΩ, V_{RL}=VDD)

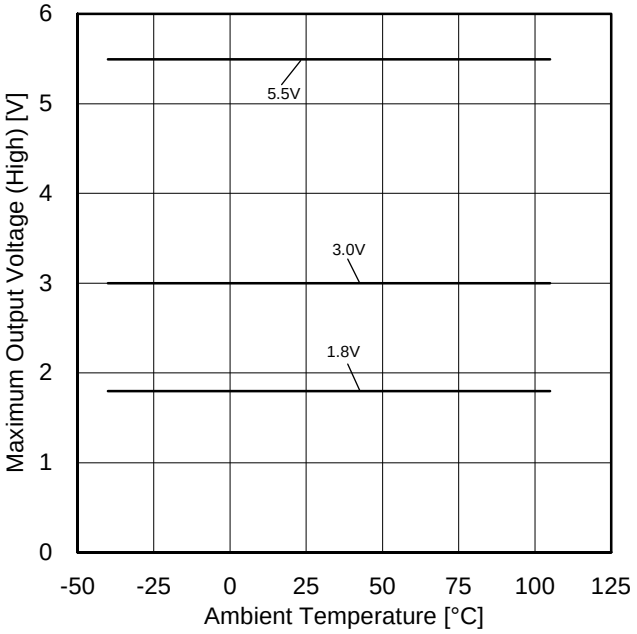


Figure 26.
Maximum Output Voltage (High) vs Ambient Temperature
(R_L=10kΩ, V_{RL}=VDD)

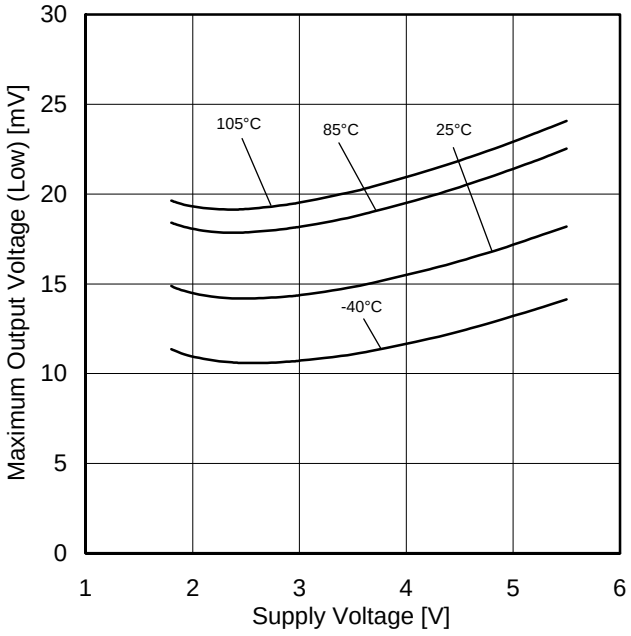


Figure 27.
Maximum Output Voltage (Low) vs Supply Voltage
(R_L=10kΩ)

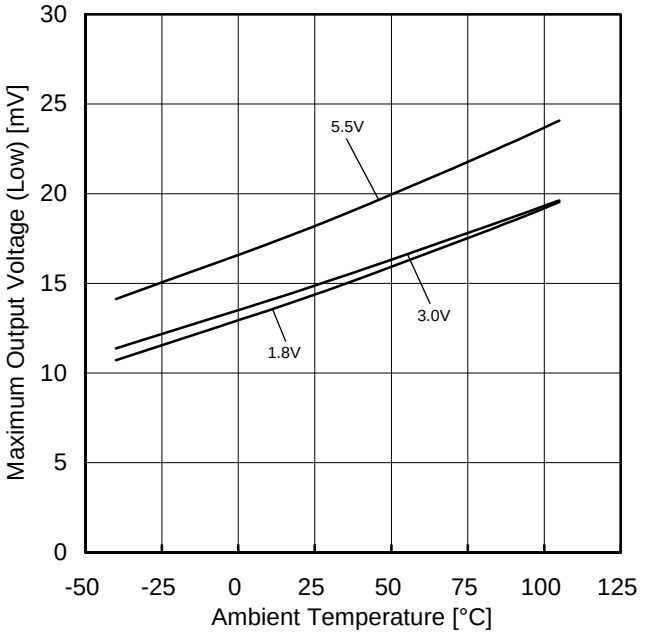


Figure 28.
Maximum Output Voltage (Low) vs Ambient Temperature
(R_L=10kΩ)

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7233F: -40°C to +85°C BU7233SF: -40°C to +105°C

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Typical Performance Curves - continued

○BU7233F, BU7233SF

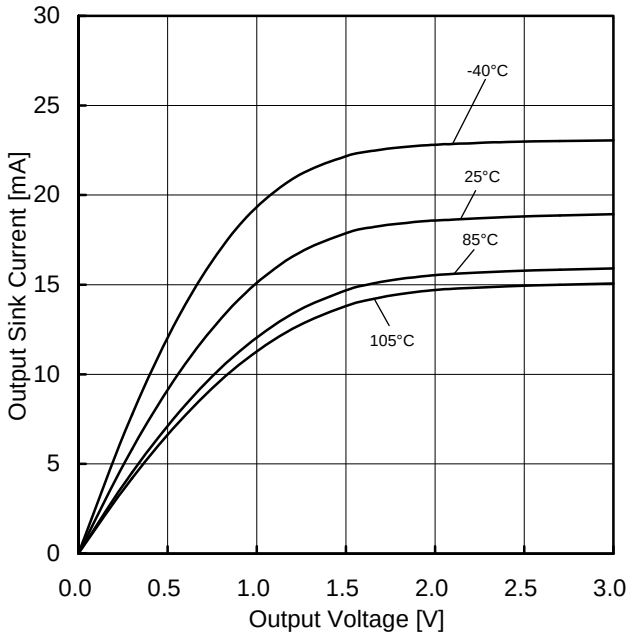


Figure 29.
Output Sink Current vs Output Voltage
(VDD=3V)

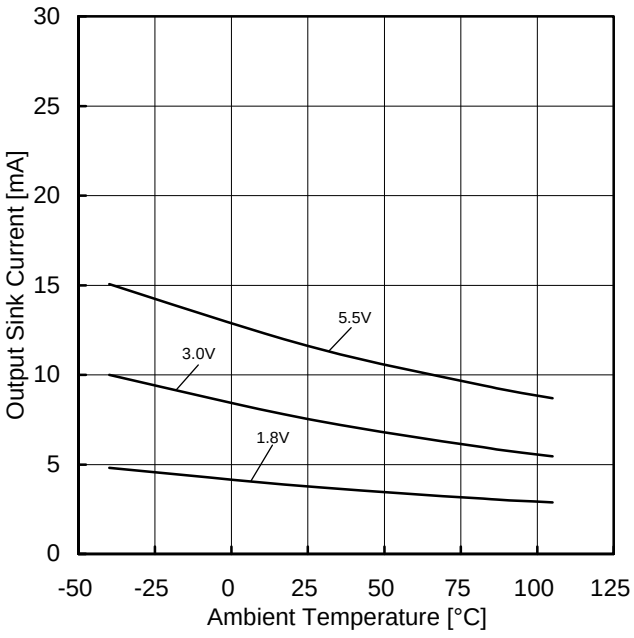


Figure 30.
Output Sink Current vs Ambient Temperature
(OUT=VSS+0.4V)

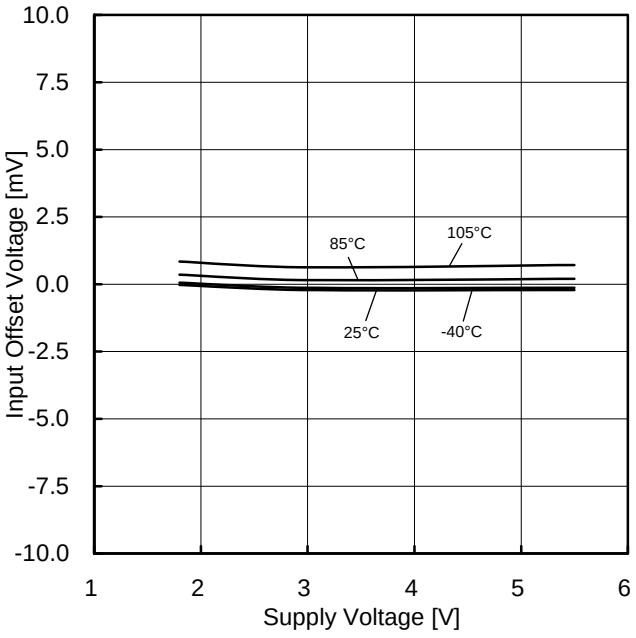


Figure 31.
Input Offset Voltage vs Supply Voltage
(V_{ICM}=VDD, E_K=-VDD/2)

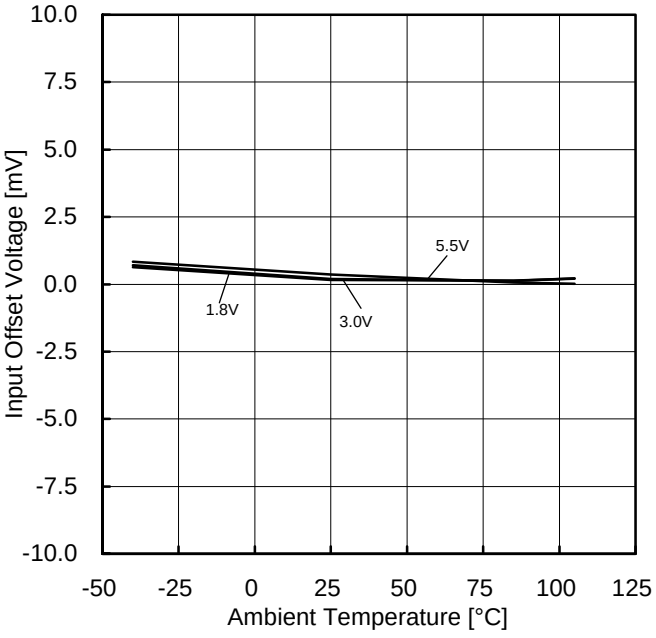


Figure 32.
Input Offset Voltage vs Ambient Temperature
(V_{ICM}=VDD, E_K=-VDD/2)

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7233F: -40°C to +85°C BU7233SF: -40°C to +105°C

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Typical Performance Curves - continued

○BU7233F, BU7233SF

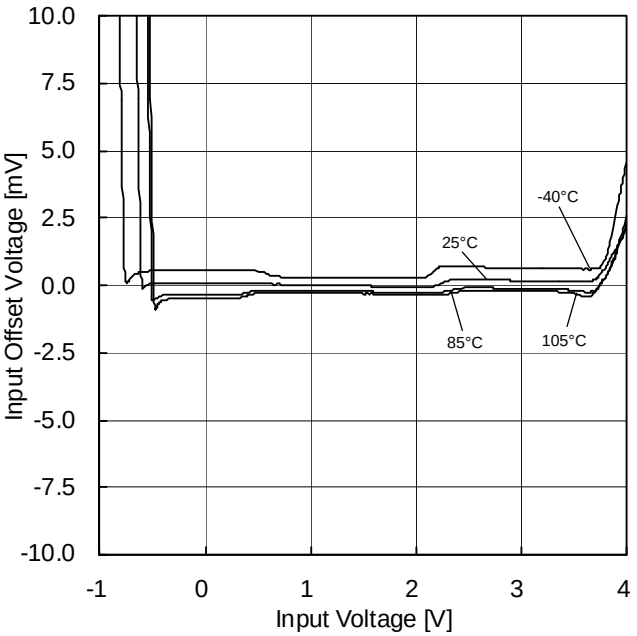


Figure 33.
Input Offset Voltage vs Input Voltage
(VDD=3V)

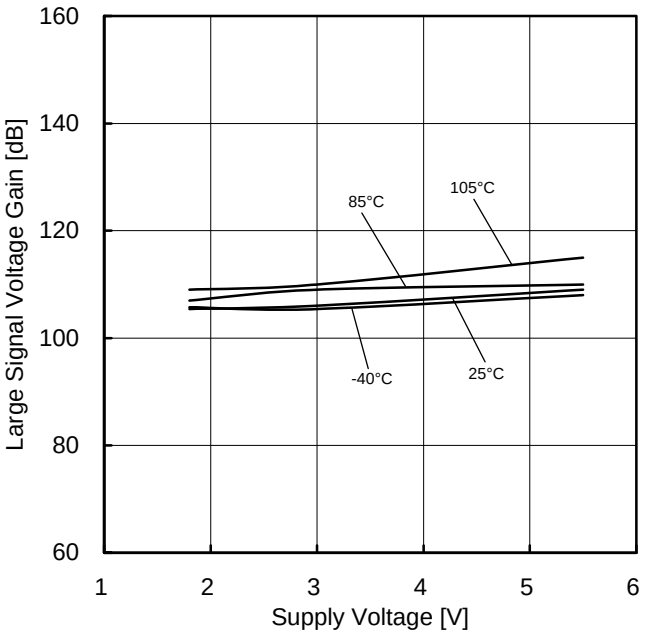


Figure 34.
Large Signal Voltage Gain vs Supply Voltage

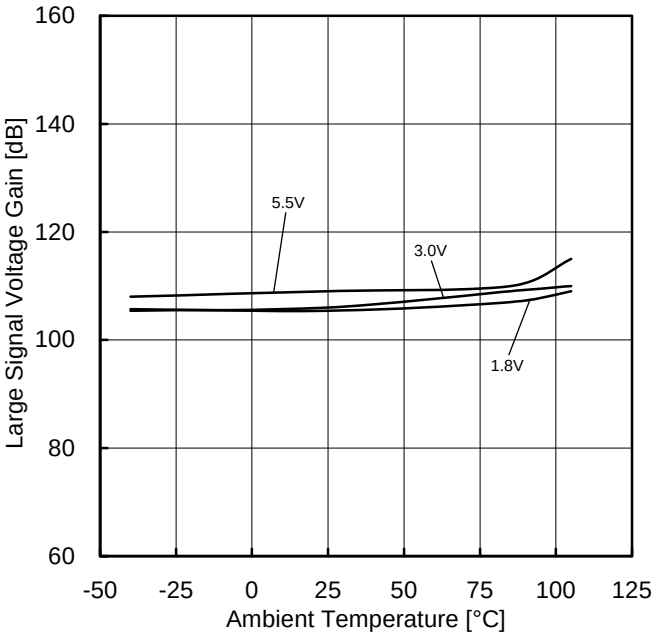


Figure 35.
Large Signal Voltage Gain vs Ambient Temperature

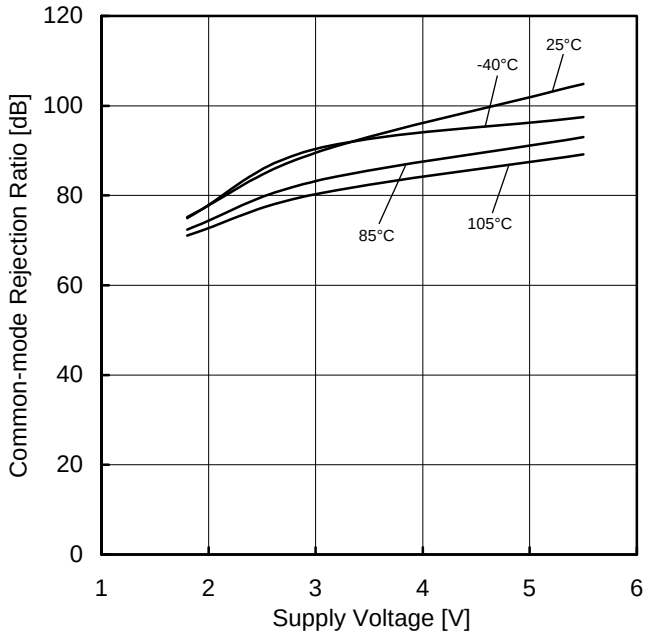


Figure 36.
Common-mode Rejection Ratio vs Supply Voltage

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7233F: -40°C to +85°C BU7233SF: -40°C to +105°C

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Typical Performance Curves - continued

○BU7233F, BU7233SF

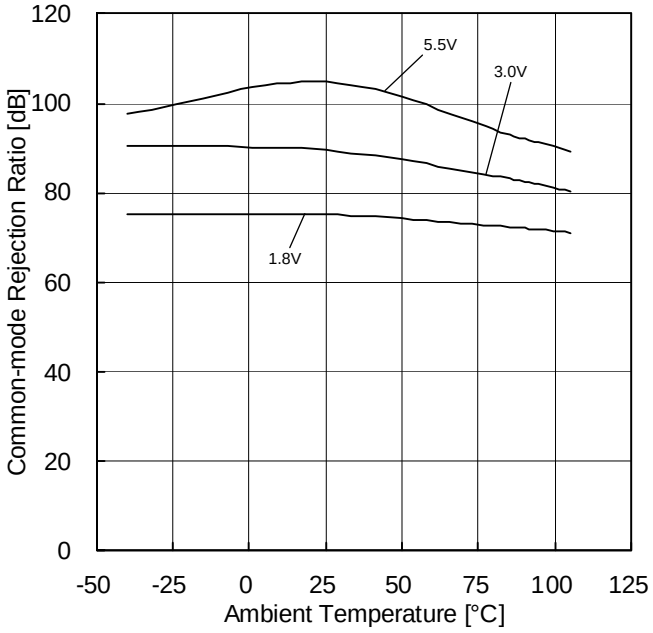


Figure 37.
Common-mode Rejection Ratio vs Ambient Temperature

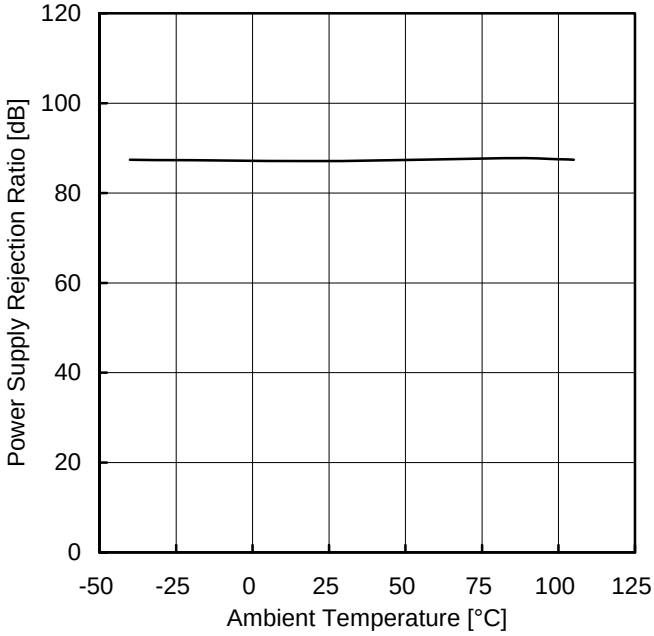


Figure 38.
Power Supply Rejection Ratio vs Ambient Temperature

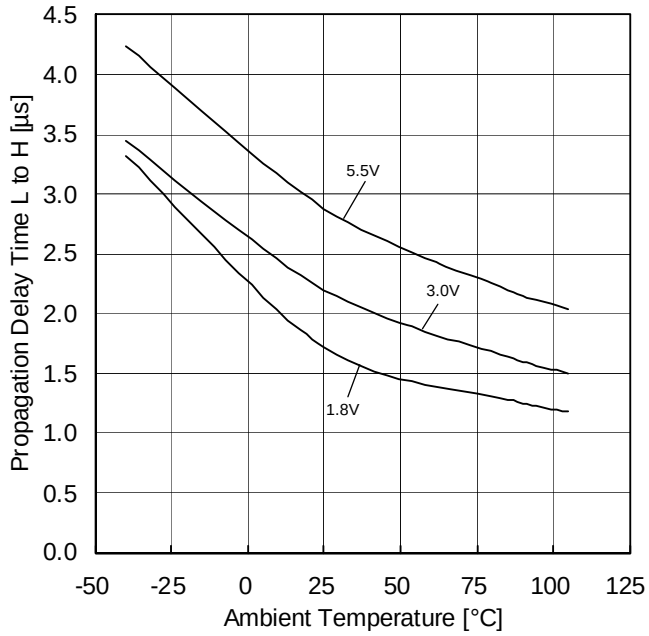


Figure 39.
Propagation Delay Time L to H vs Ambient Temperature
(R_L=10kΩ, V_{RL}=3V, C_L=15pF
IN-=1.5V, 100mV Overdrive)

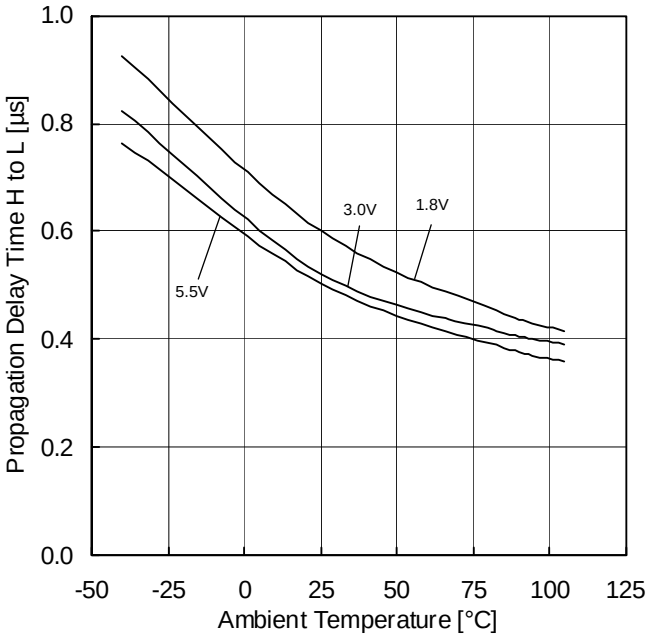


Figure 40.
Propagation Delay Time H to L vs Ambient Temperature
(R_L=10kΩ, V_{RL}=3V, C_L=15pF
IN-=1.5V, 100mV Overdrive)

(*)The above characteristics are measurements of typical sample, they are not guaranteed.
BU7233F: -40°C to +85°C BU7233SF: -40°C to +105°C

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Application Information

NULL Method Conditions for Test Circuit1

VDD, VSS, E_K, V_{ICM} Unit:V

Parameter	V_F	SW1	SW2	SW3	VDD	VSS	E_K	V_{ICM}	Calculation
Input Offset Voltage	V_{F1}	ON	ON	OFF	3	0	-0.1	0.3	1
Large Signal Voltage Gain	V_{F2}	ON	ON	ON	3	0	-0.3	0.3	2
	V_{F3}						-2.7		
Common-mode Rejection Ratio (Input Common-mode Voltage Range)	V_{F4}	ON	ON	OFF	3	0	-0.1	0	3
	V_{F5}							3	
Power Supply Rejection Ratio	V_{F6}	ON	ON	OFF	1.8	0	-0.1	0.3	4
	V_{F7}				5.5				

- Calculation -

1. Input Offset Voltage (V_{IO})

$$V_{IO} = \frac{|V_{F1}|}{1 + R_F/R_S} \quad [V]$$

2. Large Signal Voltage Gain (A_V)

$$Av = 20\mathrm{Log} \frac{\Delta E_K \times (1+R_F/R_S)}{|V_{F3} - V_{F2}|} \quad [dB]$$

3. Common-mode Rejection Ratio (CMRR)

$$CMRR = 20\mathrm{Log} \frac{\Delta V_{ICM} \times (1+R_F/R_S)}{|V_{F5} - V_{F4}|} \quad [dB]$$

4. Power Supply Rejection Ratio (PSRR)

$$PSRR = 20\mathrm{Log} \frac{\Delta VDD \times (1+ R_F/R_S)}{|V_{F7} - V_{F6}|} \quad [dB]$$

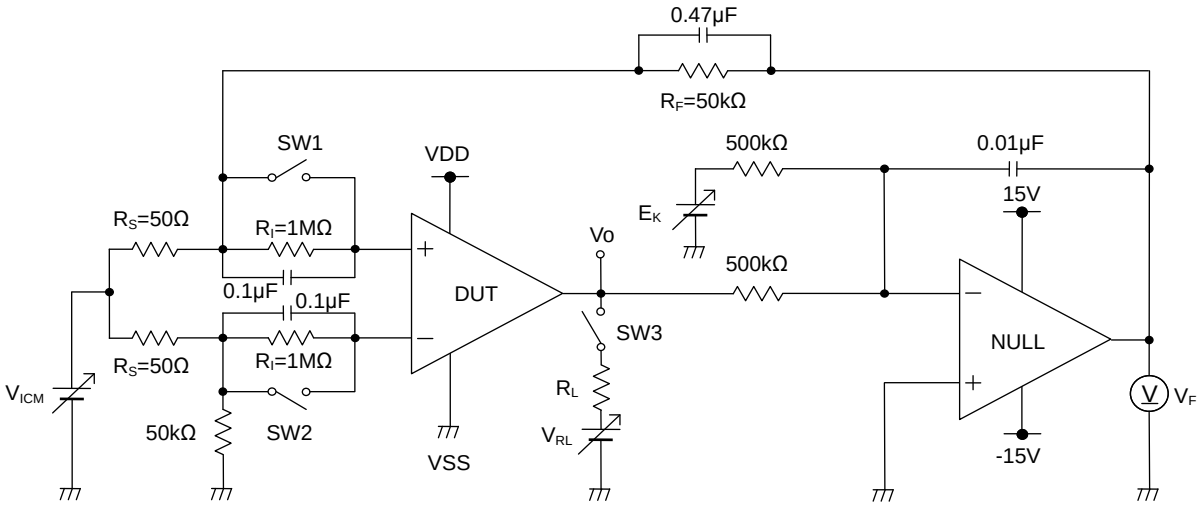


Figure 41. Test Circuit 1(One channel only)

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Application Information - continued

Switch Conditions for Test Circuit 2

SW No.	SW1	SW2	SW3	SW4	SW5	SW6	SW7	SW8
Supply Current	OFF	ON	ON	OFF	OFF	OFF	OFF	OFF
Maximum Output Voltage (R_L=10kΩ)	OFF	ON	ON	ON	OFF	OFF	ON	OFF
Output Current	OFF	OFF	OFF	OFF	OFF	ON	OFF	OFF
Response Time	ON	OFF	ON	ON	ON	OFF	OFF	ON

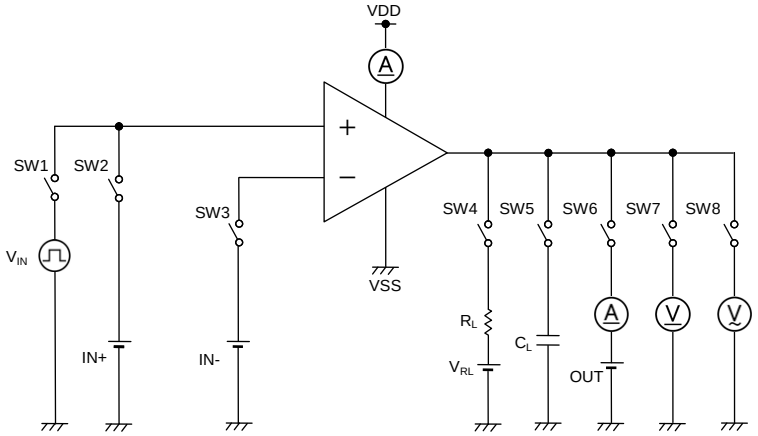


Figure 42. Test Circuit 2 (One channel only)

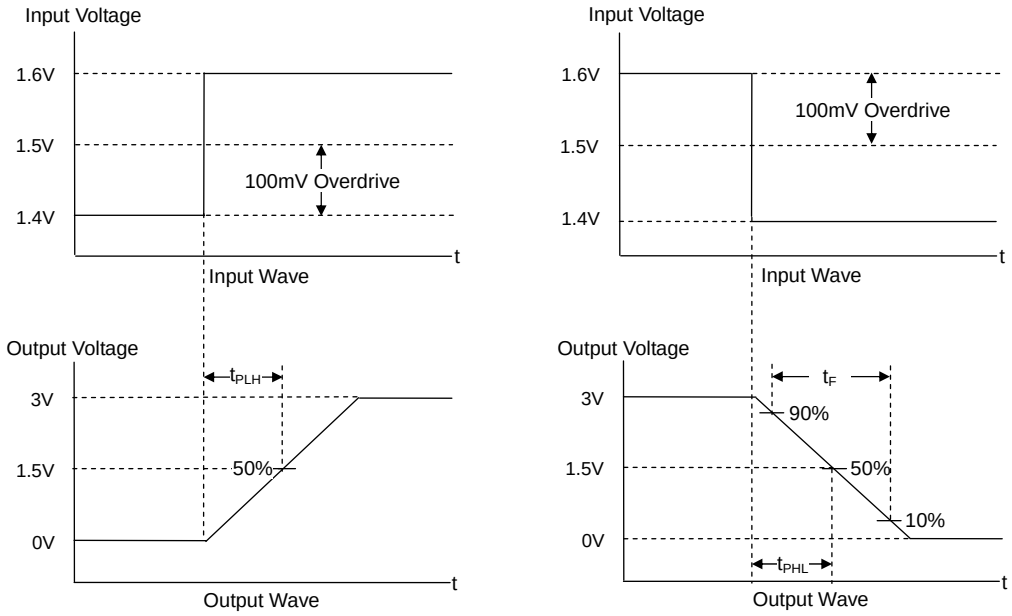


Figure 43. Response Time Input and Output Wave

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Power Dissipation

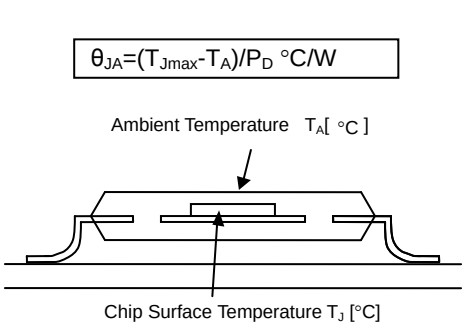
Power dissipation (total loss) indicates the power that the IC can consume at T_A=25°C (normal temperature). As the IC consumes power, it heats up, causing its temperature to be higher than the ambient temperature. The allowable temperature that the IC can accept is limited. This depends on the circuit configuration, manufacturing process, and consumable power.

Power dissipation is determined by the allowable temperature within the IC (maximum junction temperature) and the thermal resistance of the package used (heat dissipation capability). Maximum junction temperature is typically equal to the maximum storage temperature. The heat generated through the consumption of power by the IC radiates from the mold resin or lead frame of the package. Thermal resistance, represented by the symbol θ_{JA}°C/W, indicates this heat dissipation capability. Similarly, the temperature of an IC inside its package can be estimated by thermal resistance.

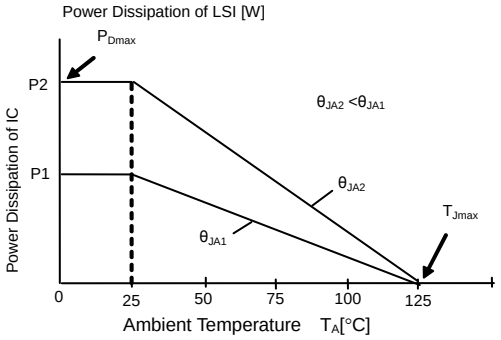
Figure 44(a) shows the model of the thermal resistance of the package. The equation below shows how to compute for the thermal resistance (θ_{JA}), given the ambient temperature (T_A), maximum junction temperature (T_{Jmax}), and power dissipation (P_D).

$$\theta_{JA} = (T_{Jmax}-T_A) / P_D \quad °C/W$$

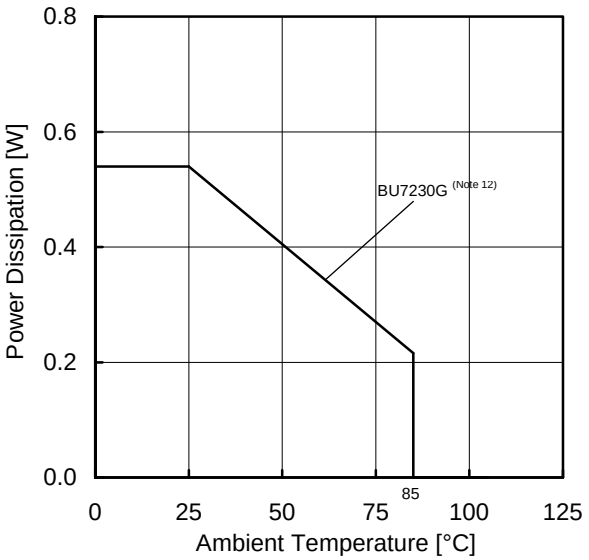
The derating curve in Figure 44(b) indicates the power that the IC can consume with reference to ambient temperature. Power consumption of the IC begins to attenuate at certain temperatures. This gradient is determined by Thermal resistance (θ_{JA}), which depends on the chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc. This may also vary even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figure 44(c) to (f) shows the derating curve for BU7230G, BU7230SG, BU7233F and BU7233SF.



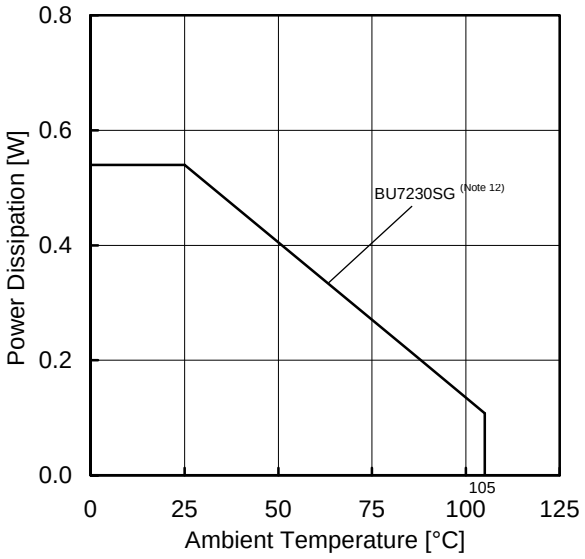
(a) Thermal Resistance



(b) Derating Curve

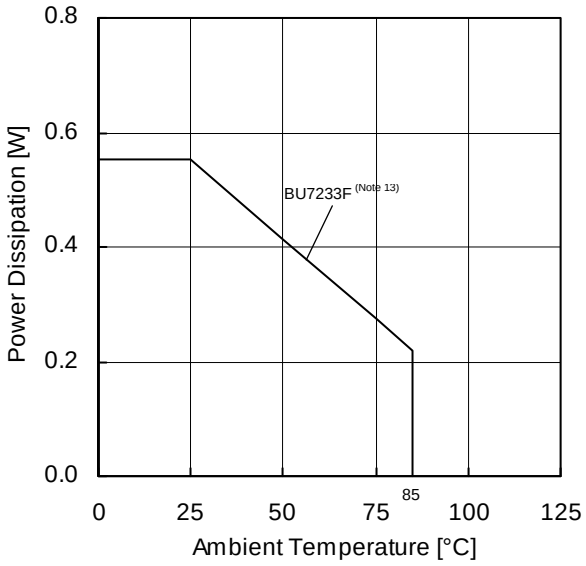


(c) BU7230G

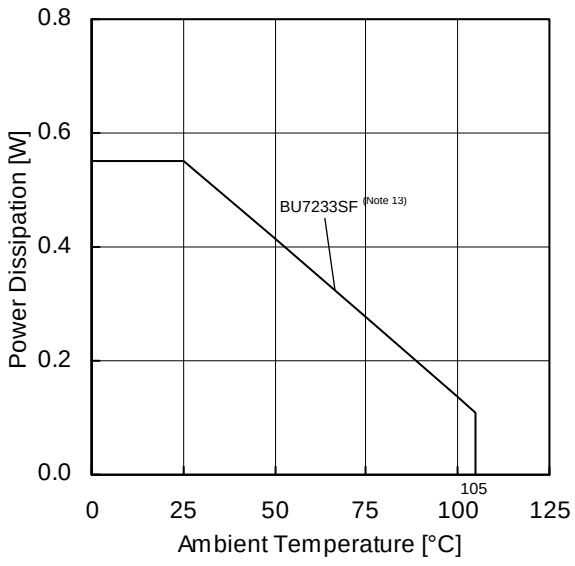


(d) BU7230SG

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(e) BU7233F



(f) BU7233SF

Figure 44. Thermal Resistance and Derating Curve

(Note 12)	(Note 13)	Unit
5.4	5.5	mW/°C

When using the unit above T_A =25°C, subtract the value above per Celsius degree. Power dissipation is the value when FR4 glass epoxy board 70mm × 70mm × 1.6mm (copper foil area less than 3%) is mounted.

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Operational Notes

1. **Reverse Connection of Power Supply**
   Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. **Power Supply Lines**
   Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. **Ground Voltage**
   Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. **Ground Wiring Pattern**
   When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. **Thermal Consideration**
   Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the P_D stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the P_D rating.

6. **Recommended Operating Conditions**
   These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. **Inrush Current**
   When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. **Operation Under Strong Electromagnetic Field**
   Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. **Testing on Application Boards**
   When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. **Inter-pin Short and Mounting Errors**
    Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

11. **Unused Input Pins**
    Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

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Operational Notes – continued

12. Regarding the Input Pin of the IC

In the construction of this IC, P-N junctions are inevitably formed creating parasitic diodes or transistors. The operation of these parasitic elements can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions which cause these parasitic elements to operate, such as applying a voltage to an input pin lower than the ground voltage should be avoided. Furthermore, do not apply a voltage to the input pins when no power supply voltage is applied to the IC. Even if the power supply voltage is applied, make sure that the input pins have voltages within the values specified in the electrical characteristics of this IC.

13. Unused Circuits

When there are unused comparators, it is recommended that they are connected as in Figure 45, setting the non-inverting input terminal to the VDD, inverting input terminal to the VSS.

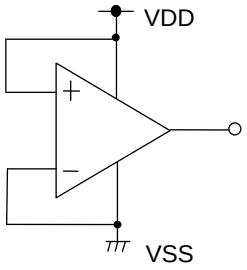


Figure 45. Example of Application Circuit for Unused Comparator

14. Input Voltage

Applying VDD+0.3V to the input terminal is possible without causing deterioration of the electrical characteristics or destruction, regardless of the supply voltage. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

15. Power Supply(single/dual)

The voltage comparator operates when the voltage supplied is between VDD and VSS. Therefore, the single supply voltage comparator can be used as dual supply voltage comparator as well.

16. Output Capacitor

If a large capacitor is connected between the output pin and VSS pin, current from the charged capacitor will flow into the output pin and may destroy the IC when the VDD pin is shorted to ground or pulled down to 0V. Use a capacitor smaller than 0.1µF between output pin and VSS pin.

17. Oscillation by Output Capacitor

Please pay attention to the oscillation by output capacitor and in designing an application of negative feedback loop circuit with these ICs.

18. Latch up

Be careful of input voltage that exceed the VDD and VSS. When CMOS device have sometimes occur latch up and protect the IC from abnormaly noise.

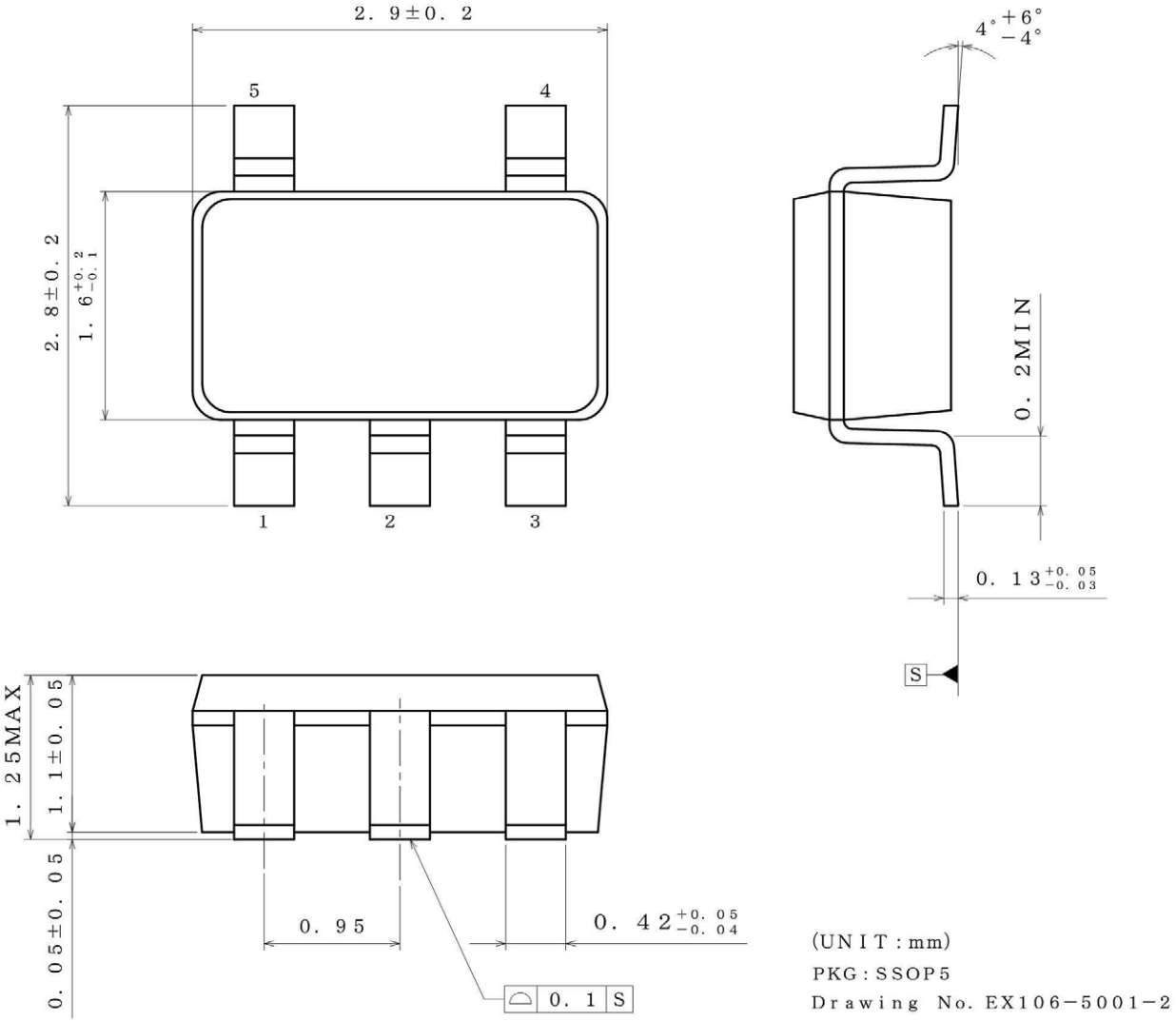
19. Open Drain Output

Please connect and use a pull-up resistor to the output since this IC has an open-drain output.

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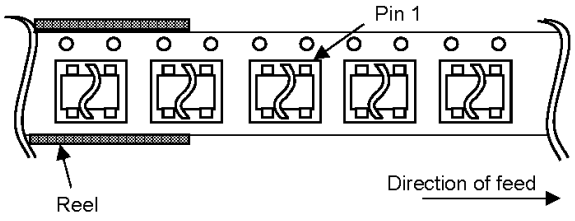
Physical Dimensions, Tape and Reel Information

Package Name	SSOP5



< Tape and Reel Information >

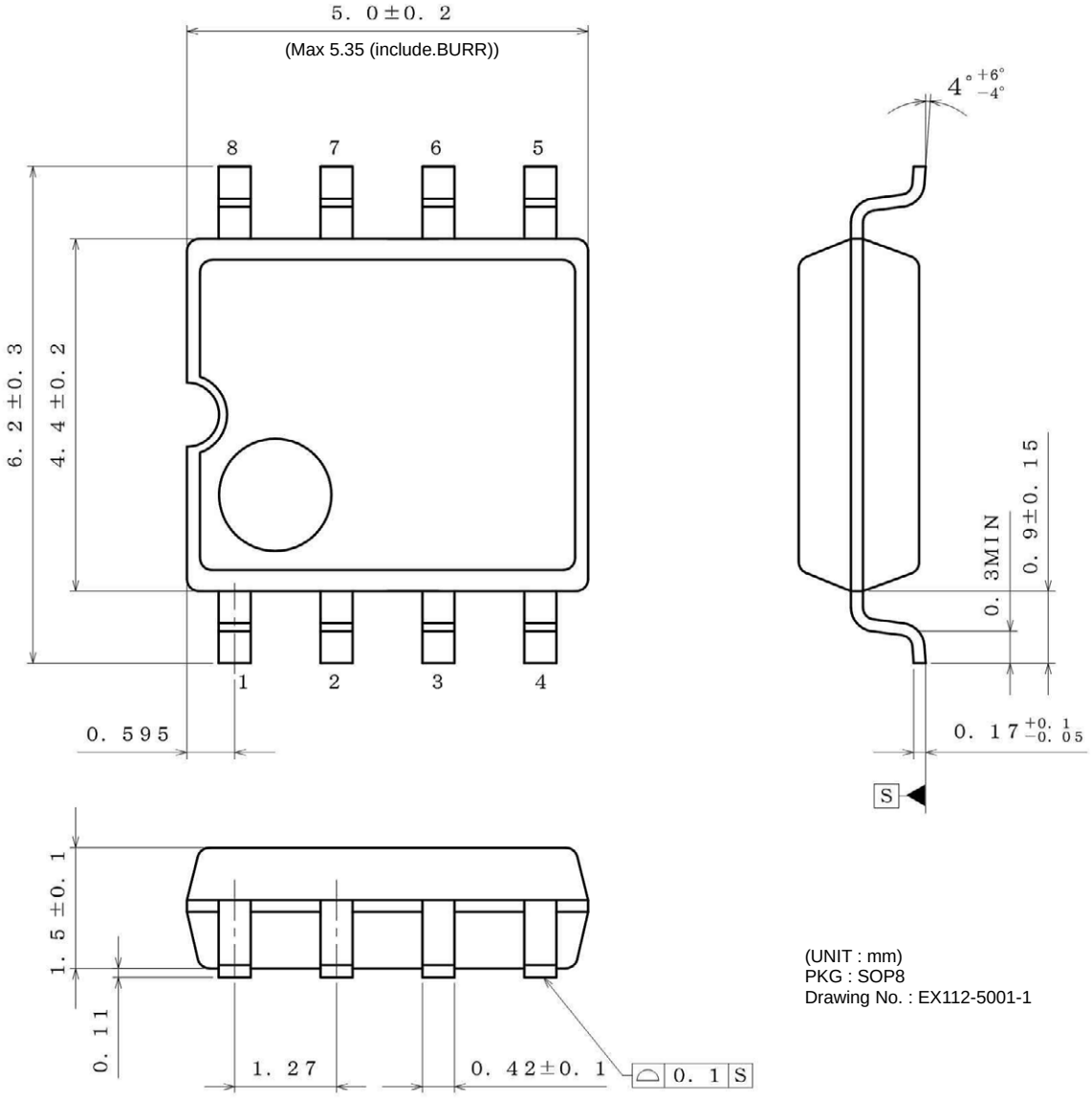
Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand)



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Physical Dimensions, Tape and Reel Information – continued

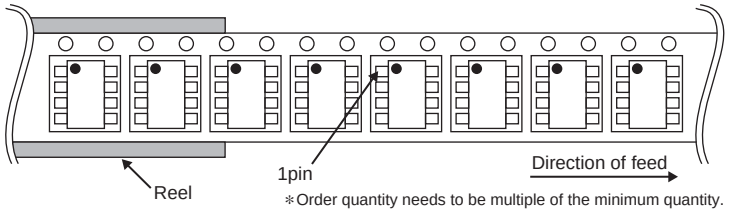
Package Name	SOP8



(UNIT : mm)
PKG : SOP8
Drawing No. : EX112-5001-1

<Tape and Reel information>

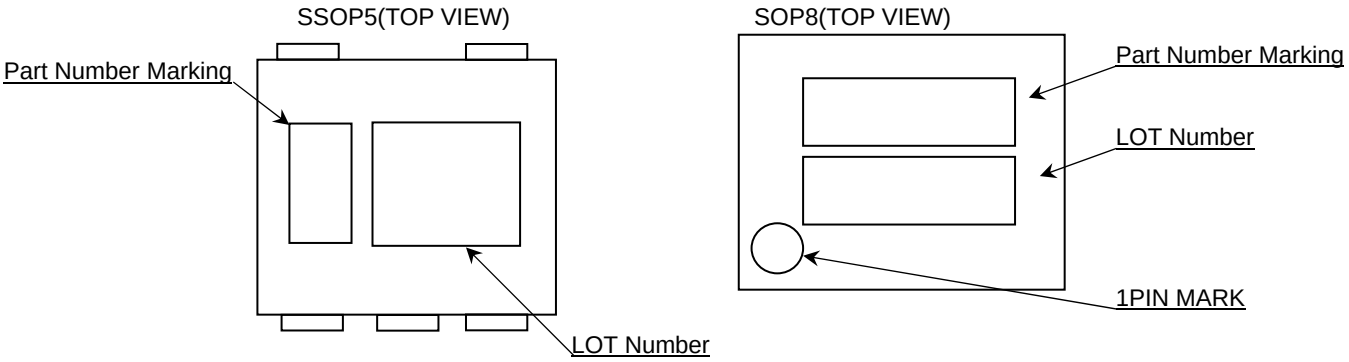
Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)



∗Order quantity needs to be multiple of the minimum quantity.

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Marking Diagram

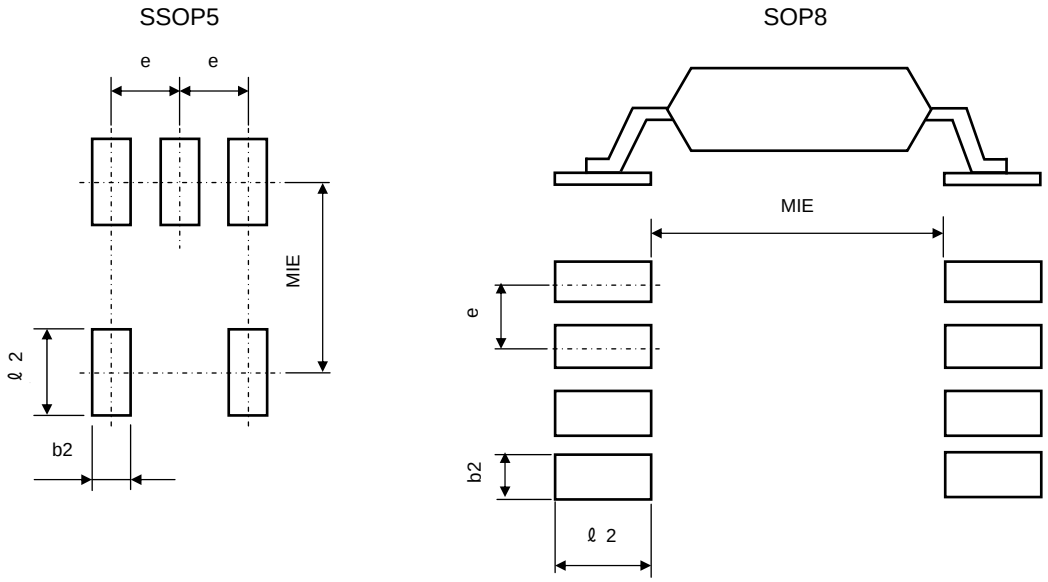


Product Name		Package Type	Marking
BU7230	G	SSOP5	H1
BU7230S			H2
BU7233	F	SOP8	7233
BU7233S			7233S

Land Pattern Data

All dimensions in mm

Package	Land pitch e	Land space MIE	Land length ≧ℓ 2	Land width b2
SSOP5	0.95	2.4	1.0	0.6
SOP8	1.27	4.60	1.10	0.76



Revision History

Date	Revision	Changes
08.Nov.2013	001	New Release
25.Dec.2013	001	Changed Propagation Delay Time H to L (Typ value)

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Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASSⅡb	CLASSⅢ
CLASSⅣ		CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
   [a] Installation of protection circuits or other protective devices to improve system safety
   [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
   [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
   [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   [f] Sealing or coating our Products with resin or other coating materials
   [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
   [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
   [b] the temperature or humidity exceeds those recommended by ROHM
   [c] the Products are exposed to direct sunshine or condensation
   [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

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